EMH4 / UMH4N / IMH4A

NPN 100mA 50V Complex Digital Transistors (Bias Resistor Built-in Transistors)

Datasheet

Parameter	Tr1 and Tr2
V_{CEO}	50V
I _{C(MAX.)}	100mA
R_1	10kΩ

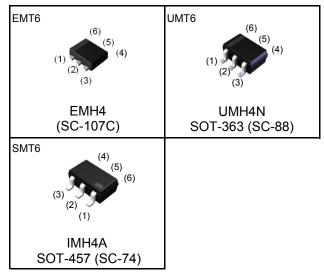
Features

- 1) Built-In Biasing Resistors.
- 2) Two DTC114T chips in one package.
- 3) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 4) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 5) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 6) Lead Free/RoHS Compliant.

Application

Inverter circuit, Interface circuit, Driver circuit

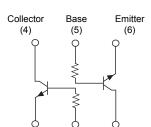
Outline



●Inner circuit

EMH4 / UMH4N

Collector Base Emitter (6) (5) (4) (1) (2) (3) Emitter Base Collector



(2)

Base

(1) Collector

(3)

Fmitter

IMH4A

Packaging specifications

- managing operations							
Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
EMH4	EMT6	1616	T2R	180	8	8,000	H4
UMH4N	UMT6	2021	TN	180	8	3,000	H4
IMH4A	SMT6	2928	T110	180	8	3,000	H4

● Absolute maximum ratings (Ta = 25°C)

<For Tr1 and Tr2 in common>

Paramete	Symbol	Values	Unit	
Collector-base voltage		V_{CBO}	50	V
Collector-emitter voltage		V _{CEO}	50	V
Emitter-base voltage		V _{EBO}	5	V
Collector current		I _{C(MAX.)} *1	100	mA
Collector Power dissipation	EMH4 / UMH4N	P _D *2	150 (Total) ^{*3}	mW
IMH4A		P_{D}	300 (Total) ^{*4}	mW
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	−55 to +150	°C

●Electrical characteristics(Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV _{CBO}	I _C = 50μA	50	-	-	V
Collector-emitter breakdown voltage	BV _{CEO}	I _C = 1mA	50	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	I _E = 50μA	5	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = 50V	-	-	0.5	μА
Emitter cut-off current	I _{EBO}	V _{EB} = 4V	1	1	0.5	μΑ
Collector-emitter saturation voltage	V _{CE(sat)}	I _C / I _B = 10mA / 1mA	-	-	0.3	V
DC current gain	h _{FE}	V_{CE} = 5V , I_{C} = 1mA ,	100	250	600	-
Input resistance	R ₁	-	7	10	13	kΩ
Transition frequency	f _T *1	V _{CE} = 10V, I _E = -5mA, f = 100MHz	-	250	-	MHz

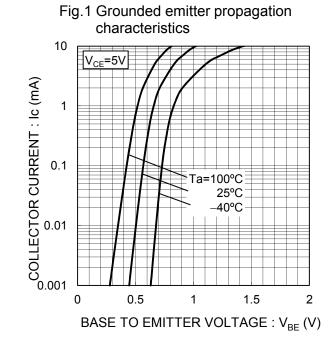
^{*1} Characteristics of built-in transistor

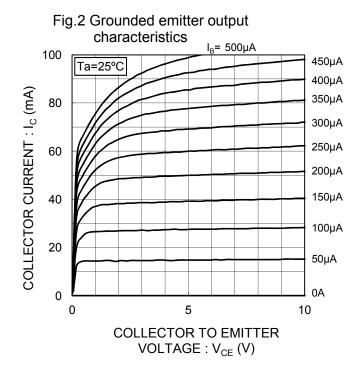
^{*2} Each terminal mounted on a reference footprint

^{*3 120}mW per element must not be exceeded.

^{*4 200}mW per element must not be exceeded.

●Electrical characteristic curves(Ta = 25°C)





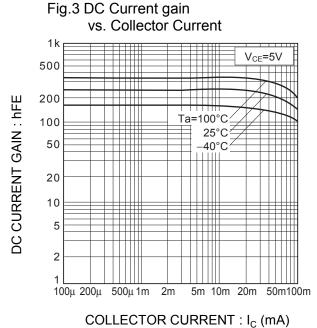
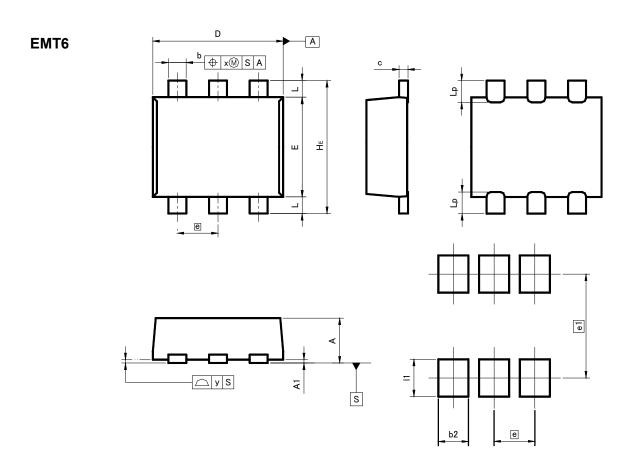


Fig.4 Collector-emitter saturation voltage vs. Collector Current $I_{\rm C}/I_{\rm B}=10$ 500m 200m **COLLECTOR SATURATION** VOLTAGE: V_{CE}(sat) (V) 100m Ta=100°C 25°C 50m 20m 10m 5m 2m 1m 100μ 200μ 500μ 1m 2m 5m 10m 20m 50m100m COLLECTOR CURRENT : I_C (mA)

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●Dimensions (Unit : mm)



Patterm of terminal position areas

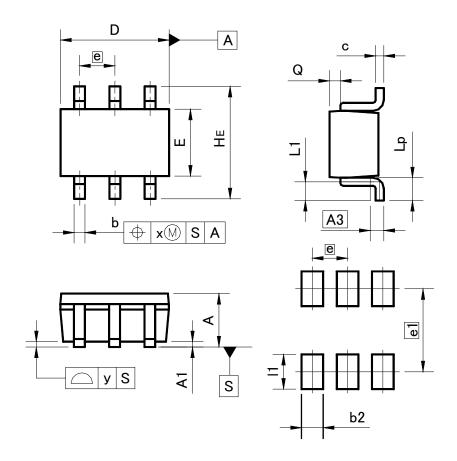
DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
A1	0.00	0.10	0	0.004
Α	0.45	0.55	0.018	0.022
b	0.17	0.27	0.007	0.011
С	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
Е	1.10	1.30	0.043	0.051
е	0.	50	0.02	
HE	1.50	1.70	0.059	0.067
L	0.10	0.30	0.004	0.012
Lp	_	0.35	_	0.014
х	_	0.10	_	0.004
٧	_	0.10	_	0.004

DIM	MILIMETERS		INCHES	
DIM MIN		MAX	MIN	MAX
e1	1.25		0.049	
b2	_	0.37	_	0.015
l1	_	0.45	_	0.018

Dimension in mm/inches

●Dimensions (Unit : mm)

UMT6



Patterm of terminal position areas

DIM	MILIM	MILIMETERS		HES
DIM	MIN	MAX	MIN	MAX
Α	0.80	1.00	ı	0.039
A1	0.00	0.10	0	0.004
A3	0.2	25	0.0	01
b	0.15	0.30	0.006	0.012
С	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
е	0.0	65	0.03	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.02
Lp	0.25	0.55	0.01	0.022
Q	0.10	0.30	0.004	0.012
х	_	0.10	_	0.004
У	_	0.10	-	0.004

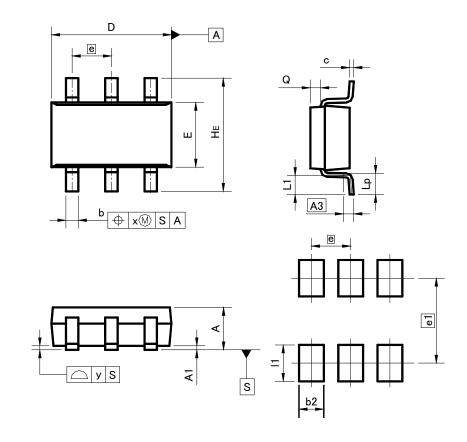
DIM	MILIMETERS		INCHES		
DIM MIN		MAX	MIN	MAX	
e1	1.55		0.06		
b2	-	0.40	ı	0.016	
11	_	- 0.65		0.026	

5/6

Dimension in mm/inches

●Dimensions (Unit : mm)

SMT6



Patterm of terminal position areas

DIM	DIM MILIME		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.00	1.30	0.039	0.051
A1	0.00	0.10	0	0.004
A3	0.3	25	0.0	01
b	0.25	0.40	0.01	0.016
С	0.09	0.25	0.004	0.01
D	2.80	3.00	0.11	0.118
Е	1.50	1.80	0.059	0.071
е	0.95		0.04	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
х		0.20		0.008
У	-	0.10		0.004

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
e1	2.10		0.08		
b2		0.60	1	0.024	
11	_	0.90	ı	0.035	

Dimension in mm/inches

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